

October 2007

FFPF04S60S

Features

- Stealth Recovery t_{rr} = 25 ns (@ I_F = 4 A)
- Max Forward Voltage, V_F = 2.6 V (@ T_C = 25°C)
- · 600 V Reverse Voltage and High Reliability
- · Avalanche Energy Rated
- · RoHS Compliant

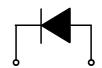
Applications

- · General Purpose
- · Switching Mode Power Supply
- · Boost Diode in Continuous Mode Power Factor Corrections
- · Power Switching Circuits

4 A, 600 V, STEALTH™ II Diode

The FFPF04S60S is a STEALTH™ II diode with soft recovery characteristics. It is silicon nitride passivated ion-implanted epitaxial planar construction. This device is intended for use as freewheeling of boost diode in switching power supplies and other power swithching applications. Their low stored charge and hyperfast soft recovery minimize ringing and electrical noise in many power switching circuits reducing power loss in the switching transistors.





1. Cathode 2. Anode

Absolute Maximum Ratings T_C = 25°C unless otherwise noted

Symbol	Parameter	Rating	Unit	
V_{RRM}	Peak Repetitive Reverse Voltage	600	V	
V_{RWM}	Working Peak Reverse Voltage	600	V	
V_R	DC Blocking Voltage	600	V	
I _{F(AV)}	Average Rectified Forward Current @ T _C = 116°C	4	Α	
I _{FSM}	Non-repetitive Peak Surge Current 60Hz Single Half-Sine Wave	40	А	
T _J , T _{STG}	Operating and Storage Temperature Range	-65 to +150	°C	

Thermal Characteristics

Symbol	Parameter	Rating	Unit
$R_{\theta JC}$	Maximum Thermal Resistance, Junction to Case	6.8	°C/W

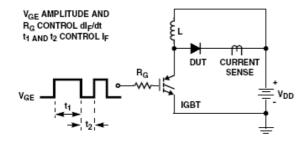
Package Marking and Ordering Information

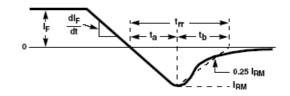
Device Marking	Device	Package	Reel Size	Tape Width	Quantity
F04S60S	FFPF04S60STU	TO-220F-2L	-	-	50

Electrical Characteristics $T_C = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Min.	Тур.	Max.	Unit	
V 1	I _F = 4 A	T _C = 25°C	-	2.2	2.6	V
V _F 1	I _F = 4 A	$T_{\rm C} = 125^{\rm o}{\rm C}$	-	1.7	-	V
. 1	V _R = 600 V	T _C = 25°C	-	-	100	μА
I _R 1	V _R = 600 V	$T_{\rm C} = 125^{\rm o}{\rm C}$	-	-	500	
t _{rr}	I _F = 1 A, di/dt = 100 A/μs, V _R = 30 V	$T_{\rm C} = 25^{\rm o}{\rm C}$	-	16	23	ns
t _{rr}			-	18	25	ns
I _{rr}	I _E = 4 A, di/dt = 200 A/μs, V _R = 390 V	T _C = 25°C	-	2	-	Α
S factor	I _F = 4 A, αι/αι = 200 A/μs, V _R = 390 V		-	0.7	-	
Q _{rr}			-	18	-	nC
t _{rr}			-	45	-	ns
Irr	$I_F = 4 \text{ A}, \text{ di/dt} = 200 \text{ A/}\mu\text{s}, V_R = 390 \text{ V}$	T _C = 125°C	-	2.8	-	Α
S factor			-	1.8	_	
Q _{rr}			-	64	-	nC
W _{AVL}	Avalanche Energy (L = 40 mH)		10	-	-	mJ

Test Circuit and Waveforms

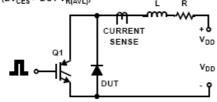


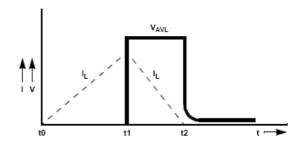


L = 40mH R < 0.1Ω

 $V_{DD} = 50V$

 $\mathsf{EAVL} = 1/2\mathsf{LI2} \; [\mathsf{V}_{\mathsf{R}(\mathsf{AVL})}/(\mathsf{V}_{\mathsf{R}(\mathsf{AVL})} - \mathsf{V}_{\mathsf{DD}})]$ Q1 = IGBT (BV_{CES} > DUT V_{R(AVL)})





Notes:
1: Pulse: Test Pulse width = 300μs, Duty Cycle = 2%

Typical Performance Characteristics

Figure 1. Typical Forward Voltage Drop vs. Forward Current

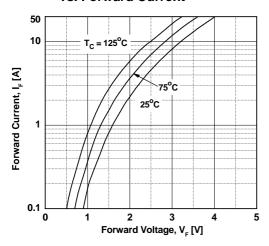


Figure 3. Typical Junction Capacitance

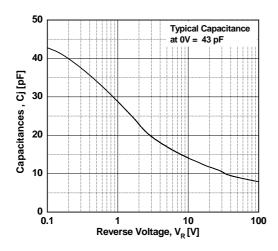


Figure 5. Typical Reverse Recovery Current vs. di/dt

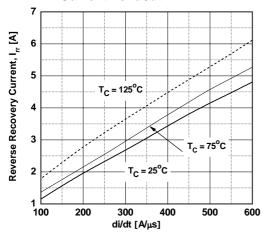


Figure 2. Typical Reverse Current vs. Reverse Voltage

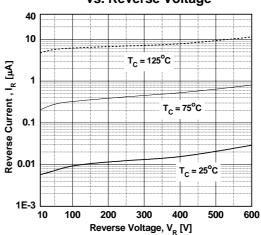


Figure 4. Typical Reverse Recovery Time vs. di/dt

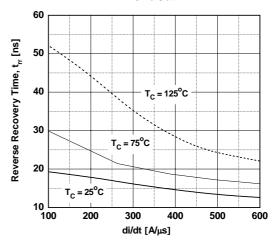
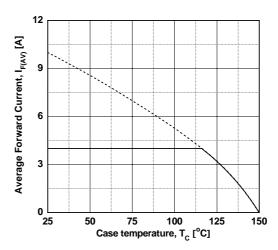
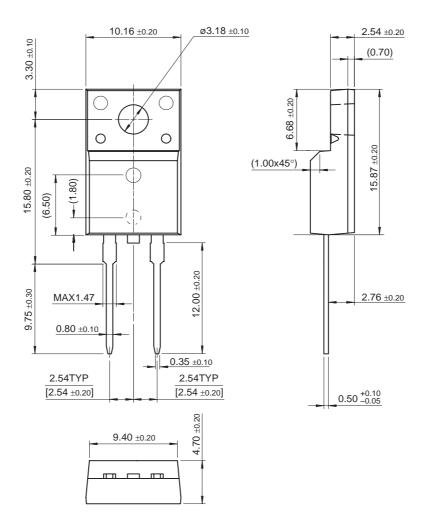


Figure 6. Forward Current Derating Curve



Mechanical Dimensions

TO-220F 2L



Dimensions in Millimeters



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Definition of Terms				
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